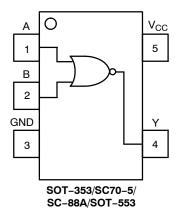
2-Input NOR Gate

The NL17SZ02 is a single 2-input NOR Gate in three tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive.

Features

- Tiny SOT-353, SOT-553 and SOT-953 Packages
- 2.4 ns T_{PD} at 5 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over-Voltage Tolerant Inputs
- Pin For Pin with NC7SZ02P5X, TC7SZ02FU and TC7SZ02AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant



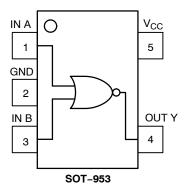


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



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MARKING DIAGRAMS

SOT-353/SC70-5/SC-88A DF SUFFIX CASE 419A



L3 = Specific Device Marking

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)



5 L3 M

XV5 SUFFIX CASE 463B

_3 = Specific Device Marking

M = Date Code



SOT-953 CASE 527AE



5 = Specific Device Code

M = Month Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

PIN ASSIGNMENT

(SOT-353/SC70-5/SC-88A/SOT-553)

| Pin | Function | |
|-----|-----------------|--|
| 1 | Α | |
| 2 | В | |
| 3 | GND | |
| 4 | Y | |
| 5 | V _{CC} | |

PIN ASSIGNMENT (SOT-953)

| Pin | Function |
|-----|-----------------|
| 1 | IN A |
| 2 | GND |
| 3 | IN B |
| 4 | OUT Y |
| 5 | V _{CC} |

FUNCTION TABLE

| Inp | Input | | | |
|-----|-------|---|--|--|
| Α | В | Y | | |
| L | L | Н | | |
| L | Н | L | | |
| Н | L | L | | |
| Н | Н | L | | |

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|----------------------|--|--|------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | -0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage (SOT-353/SC70-5/SC-88A/SOT-553 Packages) | -0.5 to V _{CC} + 0.5 | ٧ |
| V _{OUT} | | -0.5 to V _{CC} + 0.5 -0.5 to + 0.5 | V |
| I _{IK} | DC Input Diode Current | –50 | mA |
| I _{OK} | DC Output Diode Current $V_{OUT} < GND, V_{OUT} > V_{CC}$ (SOT-353/SC70-5/SC-88A/SOT-553 Packages) | ±50 | mA |
| l _{ok} | DC Output Diode Current (SOT-953 Package) V _{OUT} < GND | -50 | mA |
| I _{OUT} | DC Output Sink Current | ±50 | mA |
| I _{CC} | DC Supply Current per Supply Pin | ±100 | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| TJ | Junction Temperature Under Bias | +150 | °C |
| θ_{JA} | Thermal Resistance SOT-353 (Note 1) SOT-553 | 350 496 | °C/W |
| P_{D} | Power Dissipation in Still Air at 85°C SOT-353 SOT-553 | 186 135 | mW |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| ESD | ESD Classification Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | Class 2 Class A N/A | |
| I _{LATCHUP} | Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
 Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
 Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.

- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit | |
|---------------------------------|--|--------------------------------|--------|-----------------|------|
| V _{CC} | DC Supply Voltage | 1.65 | 5.5 | V | |
| V _{IN} | DC Input Voltage | 0 | 5.5 | V | |
| V _{OUT} | DC Output Voltage (SOT-353/SC70-5/SC-88A/SOT-553 Packages) | 0 | 5.5 | V | |
| V _{OUT} | DC Output Voltage (SOT-953 Package) | | 0 | V _{CC} | V |
| T _A | Operating Temperature Range | | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time V _{CC} = V _{CC} = | 3.0 V ± 0.3 V 5.0 V ± 0.5 V | 0 0 | 100 20 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | T, | _A = 25°(| 2 | -55°C ≤ T | A ≤ 125°C | |
|------------------|--|--|--|--|--|---|--|---|------|
| Symbol | Parameter | Condition | (V) | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | High-Level Input Voltage | | 1.65 to 1.95 2.3 to 5.5 | 0.75 V _{CC} 0.7 V _{CC} | | | 0.75 V _{CC} 0.7 V _{CC} | | ٧ |
| V _{IL} | Low-Level Input Voltage | | 1.65 to 1.95 2.3 to 5.5 | | | 0.25 V _{CC} 0.3 V _{CC} | | 0.25 V _{CC} 0.3 V _{CC} | ٧ |
| V _{ОН} | High-Level Output Voltage V _{IN} = V _{IL} or V _{IH} | $I_{OH} = -100 \mu A$ $I_{OH} = -3 mA$ $I_{OH} = -8 mA$ $I_{OH} = -12 mA$ $I_{OH} = -16 mA$ $I_{OH} = -24 mA$ $I_{OH} = -32 mA$ | 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5 | V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8 | V _{CC} 1.52 2.1 2.4 2.7 2.5 4.0 | | V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8 | | V |
| V _{OL} | Low-Level Output Voltage V _{IN} = V _{IH} or V _{OH} | $I_{OL} = 100 \ \mu\text{A}$ $I_{OL} = 3 \ \text{mA}$ $I_{OL} = 8 \ \text{mA}$ $I_{OL} = 12 \ \text{mA}$ $I_{OL} = 16 \ \text{mA}$ $I_{OL} = 24 \ \text{mA}$ $I_{OL} = 32 \ \text{mA}$ | 1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5 | | 0.08 0.20 0.22 0.28 0.38 0.42 | 0.1 0.24 0.3 0.4 0.4 0.55 | | 0.1 0.24 0.3 0.4 0.4 0.55 | V |
| I _{IN} | Input Leakage Current | V _{IN} = 5.5 V or GND | 0 to 5.5 | | | ± 0.1 | | ±1.0 | μΑ |
| l _{OFF} | Power Off Leakage Current (SOT-353/ SC70-5/SC-88A/ SOT-553 Packages) | V _{IN} = 5.5 V or V _{OUT} = 5.5 V | 0 | | | 1 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{IN} = 5.5 V or GND | 5.5 | | | 1 | | 10 | μΑ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS t_R = t_F = 3.0 ns

| | | | V _{CC} | • | Γ _A = 25°C | ; | -55°C ≤ T | _A ≤ 125°C | |
|------------------|-------------------|--|-----------------|-----|-----------------------|------|-----------|----------------------|------|
| Symbol | Parameter | Condition | (V) | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} | Propagation Delay | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$ | 1.65 | 2.0 | 5.3 | 11.5 | 2.0 | 12.0 | ns |
| t _{PHL} | (Figure 3 and 4) | $R_L = 1 M\Omega, C_L = 15 pF$ | 1.8 | 2.0 | 4.4 | 9.5 | 2.0 | 10.0 | |
| | | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$ | 2.5 ± 0.2 | 0.8 | 2.9 | 6.5 | 0.8 | 7.0 | |
| | | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$ | 3.3 ± 0.3 | 0.5 | 2.3 | 4.5 | 0.5 | 4.7 | |
| | | $R_L = 500 \Omega, C_L = 50 pF$ | | 1.5 | 2.9 | 5.0 | 1.5 | 5.2 | |
| | | $R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$ | 5.0 ± 0.5 | 0.5 | 1.9 | 3.9 | 0.5 | 4.1 | |
| | | $R_L = 500 \Omega, C_L = 50 pF$ | | 0.8 | 2.4 | 4.3 | 0.8 | 4.5 | |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Unit |
|-----------------|-------------------------------|--|---------|------|
| C _{IN} | Input Capacitance | $V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$ | >4 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 25 | pF |
| | (Note 6) | 10 MHz, V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC} | 30 | |

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

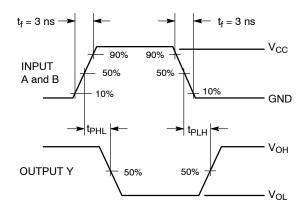
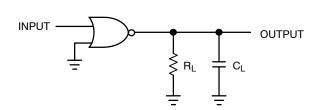


Figure 3. Switching Waveform



A 1-MHz square input wave is recommended for propagation delay tests.

Figure 4. Test Circuit

ORDERING INFORMATION

| Device | Package | Shipping [†] | |
|-----------------|-------------------------------------|-----------------------|--|
| NL17SZ02DFT2G | SC-88A/SOT-353/SC-70-5 (Pb-Free) | 3000 / Tape & Reel | |
| NLV17SZ02DFT2G* | SC-88A/SOT-353/SC-70-5 (Pb-Free) | 3000 / Tape & Reel | |
| NL17SZ02XV5T2G | SOT-553 (Pb-Free) | 4000 / Tape & Reel | |
| NL17SZ02P5T5G | SOT-953 (Pb-Free) | 8000 / Tape & Reel | |

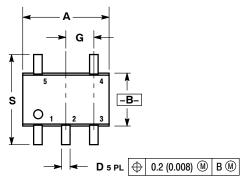
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

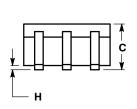
^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

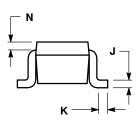
PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)

CASE 419A-02 **ISSUE L**







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

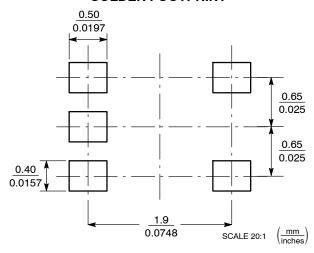
 2. CONTROLLING DIMENSION: INCH.

 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | INCHES | | MILLIN | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN MAX | | MIN | MAX |
| Α | 0.071 | 0.087 | 1.80 | 2.20 |
| В | 0.045 | 0.053 | 1.15 | 1.35 |
| C | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 | BSC | 0.65 BSC | |
| Н | | 0.004 | | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 | REF |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

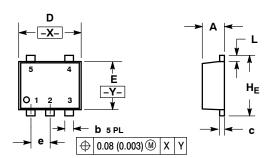
SOLDER FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

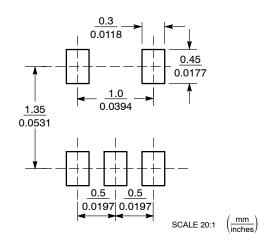
SOT-553 **XV5 SUFFIX** CASE 463B **ISSUE B**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-----------|--------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.50 | 0.55 | 0.60 | 0.020 | 0.022 | 0.024 |
| b | 0.17 | 0.22 | 0.27 | 0.007 | 0.009 | 0.011 |
| С | 0.08 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |
| E | 1.10 | 1.20 | 1.30 | 0.043 | 0.047 | 0.051 |
| е | 0.50 BSC | | | 0.020 BSC | | |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| HE | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 |

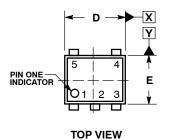
SOLDERING FOOTPRINT*

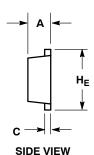


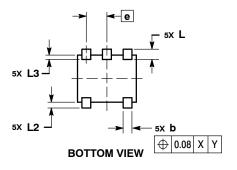
^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOT-953 CASE 527AE ISSUE E





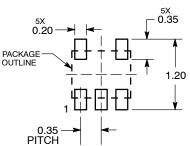


NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | | | |
|-----|-------------|-----------|------|--|--|--|
| DIM | MIN | NOM | MAX | | | |
| Α | 0.34 | 0.37 | 0.40 | | | |
| b | 0.10 | 0.15 | 0.20 | | | |
| С | 0.07 | 0.12 | 0.17 | | | |
| D | 0.95 | 1.00 | 1.05 | | | |
| Е | 0.75 | 0.80 | 0.85 | | | |
| е | | 0.35 BS | С | | | |
| HE | le 0.95 1.0 | 1.00 | 1.05 | | | |
| L | (| 0.175 REF | | | | |
| L2 | 0.05 | 0.10 | 0.15 | | | |
| L3 | | | 0.15 | | | |

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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